## Wideband Amplifier 10 MHz - 40 GHz

#### Features

- 13 dB Gain
- 50 Ω Input / Output Match
- +18 dBm Output Power
- +5 V DC, 190 mA
- Lead-Free 5 mm 9-lead LGA Package
- RoHS\* Compliant and 260°C Reflow Compatible

#### Description

The MAAM-011109 is an easy-to-use, wideband amplifier that operates from 10 MHz - 40 GHz. The device features 13 dB gain and +18 dBm of output power. Matching is 50  $\Omega$  with typical return loss better than 15 dB. This amplifier requires dual DC supplies: 5 V (190 mA) and a low current -5 V (<1 mA).

The MAAM-011109 integrates an ultra-broadband bias choke, DC blocking and bypass capacitors. Other features include a gate bias adjust pin to change current setting for power or temperature, a gain trim control pin that allows 15 dB of gain control (0 to -1V), and a temperature compensated detector pin that provides a DC voltage in relation to output power.

The MAAM-011109 is ideally suited for any application that requires 50  $\Omega$  gain from 10 MHz to 40 GHz. It is useful in applications where the incoming signal varies over a broad bandwidth such as laboratory, instrumentation, and defense applications.

This device is housed in a leadless 5 X 5 X 1.3 mm package that can be handled and placed with standard pick and place assembly equipment. The package base is a two layer laminate with overmold fully compatible with PCB environment and wash conditions. The module includes a GaAs MMIC that is fully passivated for performance and reliability.

## **Ordering Information**<sup>1,2</sup>

Part Number	Package
MAAM-011109	bulk quantity
MAAM-011109-TR1000	1000 piece reel
MAAM-011109-001SMB	Sample board

1. Reference Application Note M513 for reel size information.

2. All sample boards include 3 loose parts.

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# $RF_{IN} \xrightarrow{V_{C} V_{DET} B_{C} V_{D}} RF_{OUT}$

## **Pin Configuration**

Pin No.	Pin Name	Function	
1	RF <sub>IN</sub>	RF Input	
2	VE	-5 V Supply	
3	N/C	No Connection	
4	V <sub>G</sub>	Gate Adjust (optional)	
5	RF <sub>OUT</sub>	RF Output	
6	V <sub>D</sub>	+5 V Supply	
7	B <sub>C</sub>	V <sub>D</sub> Bypass (optional) No Connection	
8	V <sub>DET</sub>	Power Detector	
9	Vc	Gain Control	
10	Paddle <sup>3</sup>	Ground	

3. The exposed pad centered on the package bottom must be connected to RF and DC ground.

\* Restrictions on Hazardous Substances, European Union Directive 2011/65/EU.

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Functional Schematic



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Parameter	Test Conditions	Units	Min.	Тур.	Max.
Gain	0.1 GHz 2 GHz 12 GHz 20 GHz 32 GHz 40 GHz	dB		12.0 13.0 12.0 11.5 11.0 8.0	_
Isolation	0.01 - 40 GHz	dB	_	22	_
Input Return Loss	0.01 - 40 GHz	dB	_	13	_
Output Return Loss	0.01 - 40 GHz	dB	_	9	_
Noise Figure	0.01 - 40 GHz	dB	—	3.5	—
P1dB	0.1 GHz 10 GHz 40 GHz	dBm		+18 +17 +13	
Output IP3	0.1 GHz 10 GHz 40 GHz	dBm	_	+26 +24 +16	_
Bias Current	$V_{\rm D}$ = +5 V, $V_{\rm E}$ = -5 V	mA	_	170	_

#### Electrical Specifications: $T_A = +25^{\circ}C$ , $V_D = +5 V$ , $V_E = -5 V$ , $V_C = Open$ , $Z_{IN} = Z_{OUT} = 50 \Omega$

#### Absolute Maximum Ratings<sup>4,5,6</sup>

Parameter	Absolute Max.
Input Power	+17 dBm
Drain Supply Voltage	+8 Volts
Junction Temperature <sup>7</sup>	+150°C
Operating Temperature	-40°C to +85°C
Storage Temperature	-65°C to +150°C

- 4. Exceeding any one or combination of these limits may cause permanent damage to this device.
- 5. MACOM does not recommend sustained operation near these survivability limits.
- 6. Operating at nominal conditions with  $T_{\rm J}$   $\leq$  150°C will ensure MTTF > 1 x 10^6 hours.
- 7. Junction Temperature (T<sub>J</sub>) = T<sub>C</sub> +  $\Theta_{JC}$  \* ((V \* I) (P<sub>OUT</sub> P<sub>IN</sub>)) Typical thermal resistance ( $\Theta_{JC}$ ) = 21°C/W
  - a) For  $T_c = 25^{\circ}C$ ,

 $T_J = 43^{\circ}C \otimes 5 V$ , 190 mA,  $P_{OUT} = 20 \text{ dBm}$ ,  $P_{IN} = 7 \text{ dBm}$ b) For  $T_C = 85^{\circ}C$ ,

T<sub>J</sub> = 103°C @ 5 V, 190 mA, P<sub>OUT</sub> = 20 dBm, P<sub>IN</sub> = 7 dBm

#### Handling Procedures

Please observe the following precautions to avoid damage:

#### **Static Sensitivity**

Gallium Arsenide Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these Class 1B devices.

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<sup>2</sup> 

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#### Rev. V2

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#### **Application Schematic**



#### **Recommended PCB Layout**



#### **Parts List**

Component	Value	Package
C1	0.22 μF	0201
L1	470 Ω	0603

## Application Information for DC & pins

For proper MAAM-011109 operation a DC voltage must be applied at the V<sub>E</sub> (-5 V) and V<sub>D</sub> (+5 V) pins *in that order*. The optional V<sub>G</sub> pin maybe used to override the automatic V<sub>E</sub> bias network to hard set the gate. Adjusting V<sub>G</sub> from -0.2 V to -0.6 V will change the quiescent current. If V<sub>G</sub> is used, V<sub>E</sub> should be left unconnected.

The  $V_C$  pin is typically left unconnected unless gain control or output power limiting is desired. Please refer to the "Variable Gain/Limiting" section for detailed usage.

The V<sub>D</sub> pin should be bypassed with at least 0.1  $\mu$ F for stability. For operation below 100 MHz a ferrite bead (Murata BLM18BB471) must be inserted between the V<sub>D</sub> pin and bypass capacitor. The V<sub>G</sub> and V<sub>C</sub> pins must also be bypassed with a 0.1  $\mu$ F capacitor if operating below 100 MHz.

The  $V_{DET}$  pin is typically left unconnected unless a voltage reference is desired that is correlated to the output power. Please refer to the "Internal Detector" section for detailed usage.

The  $B_C$  pin is typically left unconnected unless gain bandwidth and shape change is desired. Please refer to an application note on this pin.

The input and output pins are internally DC blocked. No more than +/- 12 V should ever be present on these RF only pins.

The backside paddle of the MAAM-011109 should be connected to ground with as many vias as possible to maximize high frequency performance, thermal dissipation, and stability.

<sup>3</sup> 

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# Wideband Amplifier 10 MHz - 40 GHz

# **Typical Performance Curves over Temperature**



Input Return Loss



**Output P1dB** 





Frequency (GHz)

**Output Return Loss** 





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# Wideband Amplifier 10 MHz - 40 GHz

## Typical Performance Curves vs. Voltage and Current



Input Return Loss



Output P1dB







**Output Return Loss** 





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# Wideband Amplifier 10 MHz - 40 GHz

# Typical Performance Curves



Stability Factor







Gain vs. Frequency, Vc = -0.9 to 1.1 V



**Output Saturated Power** 







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# Wideband Amplifier 10 MHz - 40 GHz

## **Typical Performance Curves**

V<sub>DET</sub> vs. Output Power



Current vs. Gate Voltage



For further information and support please visit: <u>https://www.macomtech.com/content/customersupport</u>

V<sub>DET</sub> vs. Output Power @ 2 GHz



Current vs. Control Voltage

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